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Structural, Electronic and Thermoelectric Behaviour of CaMnO$_3$ and CaMnO$_{(3-\delta)}$

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Abstract

First principle calculations were employed to investigate the orthorhombic perovskite CaMnO$_3$ and the impact of reduced oxygen content on the electronic, structural and thermoelectric properties. On partial reduction to CaMnO$_{2.75}$, oxygen vacancies order in a zig-zag arrangement and a further reduction to CaMnO$_{2.5}$, is predicted to form a brownmillerite-like structure. We found that reduced structures have a large volume expansion which can be related to the formation of domains and cracking in experimental samples. On calculating the thermoelectric properties, we found that the partially reduced structures have more favourable Seebeck coefficients compared to the highly reduced structures. The structures can also be separated into two classes based on the resistivity showing low or high resistance depending on the oxygen vacancies arrangement and content. However none of the intrinsically doped structures shows enhanced power factors and ZT.

Keywords: Calcium Manganate, Thermoelectric Material, Transport Properties, DFT, Boltzmann Transport Theory, Perovskite, Brownmillerite.

I. Introduction

Energy production from current technologies, particularly fossil fuels has a negative impact on the environment and on the human living conditions while global energy consumption increases. The development of alternative sources and the improvement of the energy conversion technologies are therefore desirable. Thermoelectric (TE) devices convert waste heat into electrical energy and can provide supplemental energy. TE generation is limited by the low energy conversion efficiency which depends on the design of the device, on the operating temperatures and on the thermoelectric figure of merit of the material, ZT. The figure of merit given in Equation 1, is dimensionless and comprises the Seebeck coefficient or thermopower, $S$, the electrical conductivity, $\sigma$, the electronic ($\kappa_e$) and lattice ($\kappa_l$) contributions to the thermal conductivity and the absolute temperature, $T$.

$$ZT = \frac{\sigma S^2}{(\kappa_e + \kappa_l)} T$$  

(1)

Devices that implement materials with ZT > 1 are considered most cost effective. A TE generator comprises alternating series of p- and n-type conducting materials. Thus the TE compatibility factor, $s = |(1+ZT)^{0.5}-1|/(ST)$, was introduced to define the conversion efficiency of the generator. To maximize the efficiency, the $s$ values of the n- and p-type materials should be similar within the operating temperature range and their ratio generally < 2. Furthermore it is of extreme importance that the ZT over the working temperature range of the TE device is constant.

Obtaining a large ZT is complicated by three interconnected properties that influence the performance of the material: improvements in one property can be offset by changes in the other properties. Thus three key properties need to be examined for improved efficiency. The Seebeck coefficient should be large as it related to the voltage generated by the TE material in the temperature gradient, the electrical conductivity should be high to minimize ohmic losses and the thermal conductivity should be low to maintain the thermal gradient.

The largest ZT have been achieved with chalcogenites and skutterudites but their stability at high temperatures and under oxidizing conditions is poor and the toxicity of these compounds is also a major issue. Oxide materials can address these problems and both p- and n-type oxide materials have been exploited for use in...
thermoelectric devices. However issues with their usage still remain, although for performance they are promising.

Amongst the candidates are layered complex oxides, doped zinc oxide derivatives, and perovskite-type oxides. The major advantage of the perovskites is the flexibility of the doping on either A and B sites covering most of the periodic table, which provides for a broad selection of material-property combinations. Simple perovskites are not strong potential TE materials as they are normally good insulators with high Seebeck coefficients (S). However, improvements in the TE properties are achievable through cation substitution. 

We focus on the n-type perovskite CaMnO$_3$ (CMO). The efficiency of superstructures based on CMO has been discussed in the literature but little is known about the effect of oxygen partial pressure on the thermoelectric properties. CMO samples are affected by cracking possibly due to a phase change around 900°C and the inhomogeneity with areas generally rich in oxygen vacancies. However as TE materials can be improved by means of nanostructuring and band engineering, it is of extreme importance to understand the properties of oxygen poor compositions within the sample. CMO gives a perfect case study where the properties of different samples differ broadly depending on the oxygen vacancies ordering. Even though most studies focused on the cubic phase (Ref therein), ordering of oxygen vacancies was seen for the orthorhombic phase by Reller.

In the present paper, we first review the structural and magnetic properties of CMO and then assess its thermoelectric properties as a function of the oxygen composition, using first-principles electronic structure simulations and the Boltzmann transport theory.

II. Methodology

The calculation of the self-consistent Hubbard $U_{ef}$ parameter within the PBE-GGA functional for the transition metal Mn, was performed using the Quantum Espresso code using the linear response approach. The parameter was calculated for two compositions, CaMnO$_3$ and CaMnO$_2$. The $U_{ef}$ parameter depends on the configuration and the local coordination but it is accepted to average the values if the environment does not change dramatically. Convergence was reached for a K-points grid of 4x4x4 and a cut off of 50 Ry. The $U_{ef}$ parameters were 4.14 and 3.84 eV for the pure and the defective structures respectively. Hence the value of 4 eV was allowing us to reproduce the experimentally determined density of state and the correct stability of the different magnetic phases of CMO. It is worth noting that a $U_{ef}$ of 3 was used in a previous study derived by fitting to HSE results for cubic CMO and later applied to strained orthorhombic CMO successfully.

Geometry optimization was performed using spin-polarized generalized-gradient approximation (GGA) and the projector augmented wave (PAW) approach as implemented in the VASP code. The exchange correlation functional applied was the PBE with the inclusion of the Hubbard $U$ term using the Liechtenstein approaches (U=5 eV and J=1 eV since the exchange interaction is poorly screened in solids, an approach extensively justified in previous work). The GGA+U methodology enables the approach to account for the presence of the localized Mn$^{3+}$ states. 3D boundary conditions were used throughout and the cutoff energy for the plane wave basis was 550 eV with the Brillouin zone sampled using a 6x6x6 Monkhorst-Pack grid to ensure convergence. The larger cutoff of 550 eV, relative to that of 400 eV required for fixed cell calculations, removes the effect of errors due to the Pulay stress during cell relaxation. Relaxation of the structure for all atoms was deemed to have converged when the forces were below 0.01 eVÅ$^{-1}$. Similarly, the lattice vectors were adjusted until all element of the stress tensor was less than 0.05 kbar.

The electronic structures for all the compositions were calculated using the full-potential linearized augmented plane wave method as implemented in WIEN2k. The exchange correlation functional (PBE) were taken within the GGA+U. The APW+lo method expands the Kohn-Sham orbitals inside the atomic muffin-tin (MT) spheres and plane waves in the interstitial region. The muffin-tin radii were set to 2.09, 1.84 and 1.63 Bohr for Ca, Mn and O respectively. The energy convergence criterion was set to 10$^{-5}$ Ry. For the calculation of transport properties 4896 K-points in the irreducible wedge of the Brillouin zone. The density of states (DOS) was obtained using the tetrahedron method. This application of the all-electron code ensures the high quality of the band structure needed to evaluate the transport properties.

Electronic transport calculations were evaluated by solving the semi-classical Boltzmann transport equation within the relaxation time ($\tau$) and the “rigid band approach” approximation as implemented in the program package BoltzTraP. This approximation allows us to calculate all transport properties with respect to the relaxation time ($\tau$) with the exception of the Seebeck coefficient that can be calculated on an absolute scale. Discussion of the choice of relaxation time will be given in the section $\nu$ of results.

The lattice component of the thermal conductivity was calculated using the Phonopy code. As the calculation is computationally expensive only the lattice thermal conductivity of stoichiometric CMO was evaluated. Atomic displacements of 0.01Å were employed to obtain the force constants for a single unit cell containing 20 atoms. The numerical calculation was carried out with a 6 x 6 x 6 sampling mesh and a $\sigma$ value of 0.1 THz. Detailed description of the method can be found in Skelton et al.

It is worth noting that as the materials described here are anisotropic, all of the thermoelectric properties will also show direction dependence. However, as the material synthesised experimentally is polycrystalline and
single crystals with homogeneous compositions have not yet been prepared, we report the experimental relevant scalar quantity.

Figures were drawn using the program VESTA 45.

III. Results and Discussion

i. Stoichiometric CaMnO₃

CMO adopts the orthorhombic structure with space group Pnma 46, shown in Figure 1, from ambient temperature over 1000 K 47. Tetragonal 15 and rhombohedral phases were also suggested 18. Properties of pure and doped CMO have been discussed previously 48 49. CMO shows a G-type antiferromagnetic (AFM) order at T lower than 123 K with the value of the Mn³⁺ moment of 2.65 μB 50. Coexistence of different magnetic orders was reported in CaMnO₃, nanoparticles with AFM in the core and ferromagnetism (FM) in the shell 51. Previous first-principles calculations on CaMnO₃ focused both on the cubic phase 26 52 53 54 55 and on the orthorhombic phase 27 56 57 58 59.

Figure 1. Perovskite PNMA CaMnO₃. Purple octahedra are Mn⁴⁺. Ca in teal.

We considered A-, C-, and G-type antiferromagnetic with spin aligned along 010, 101 and 111 directions respectively, and ferromagnetic (FM) structures for stoichiometric CMO using the collinear magnetic ordering. All magnetic ordering schemes resulted in insulating structures (charge transfer insulator) with the G-AFM the most stable 50. Table I summarizes the optimized lattice constants, magnetic moment, band gap and energies of different magnetic structures per formula unit with reference to that of G-AFM. The agreement with experiments 46 25 50 and previously reported ab initio calculations 55 59 56 is excellent.

Table 1. Optimized lattice constants (Å), magnetic moment, band gap (eV) and energies of the magnetic structures per formula unit with reference to that of G-AFM (eV). Exp. from Refs 46 25 50

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ii. Reduced CaMnO₃

One of the features of CMO is that it can be readily reduced 15. CaMnO₃₋δ are n-type semiconductors with formation of Mn³⁺ ions upon removal of oxygen. Enthalpy of formation for oxygen vacancies (Vo) was measured to be 1.85±0.07 eV 60. Tensile strain has been found to lower the formation energy of oxygen vacancies opening routes to engineering vacancy ordering in artificial superstructures 14 15 16 27.

Systems with different oxygen vacancies arrangements of reduced CMO were investigated with composition CaMnO₂,₇₅ and CaMnO₂,₅. We have assumed the structure in a GFM ordering as single crystals of reduced cubic CMO were found to be GFM at low T. Furthermore even though at high T CMO becomes paramagnetic, it was shown that the antiferromagnetic order was an excellent approximation of the actual PM order for UO₂ 61.

Upon relaxation all structures show expansion in volume as experimentally expected 62. The enthalpy of formation of oxygen vacancies was calculated following the chemical reaction 2Mn⁺⁺ₓ+O₂⁻ → 2Mn⁺⁺ₓ₋₁+V₀ + 1/2O₂(γ) while the heat of reduction was calculated following the CaMnO₃ → CaMnO₃₋δ + 1/2O₂(γ) 63 with the binding energy of O₂ gas phase molecule in its triplet state (~9.86 eV derived from DFT calculation using a cut off of 50 Ry and a dipole corrections in all directions).

Figure 2. Side views of configuration (a) zig-zag and (b) line for CaMnO₂,₇₅. Top view of the oxygen vacancy (Vo) arrangements (c) for the zig-zag and (d) line configurations. The zig-zag and linear arrangements are shown with red line to help visualization. Purple octahedra and blue squared pyramids are Mn⁴⁺ and Mn⁵⁺ respectively. Ca in teal.

Two structures, displayed in Figure 2, were considered for the composition CaMnO₂,₇₅ as there are two inequivalent oxygen positions in within the octahedral coordination of Mn atoms to give rise to significantly different structures. Both configurations have planes of
Mn$^{3+}$ but while one has a zig-zag pattern of oxygen vacancies as shown in Figure 2(c) the other one shows a linear arrangement of oxygen vacancies (Figure 2(d)). For simplicity we refer to them as zig-zag and line configurations respectively. Mn$^{3+}$ is always in the 5-fold squared pyramidal coordination while Mn$^{4+}$ is in the octahedral coordination. The volume expansions upon reduction are 2.63% and 1.93% for the zig-zag and line configurations respectively. The enthalpies of formation of Vo for zig-zag and line configurations of CaMnO$_{2.75}$ are 2.09 and 2.16 eV respectively while the heats of reduction from stoichiometric CaMnO$_3$ are 0.52 and 0.54 eV respectively.

![Figure 3. Configurations (a), (b), (c) and (d) for CaMnO$_{2.5}$. Polyhedra of Mn in purple. Ca in teal.](image)

Different configurations of oxygen vacancies were considered for CaMnO$_{2.5}$. We modelled a brownmillerite-like structure within the stoichiometric unit cell size (Fig. 3a) and a brownmillerite structure for comparison doubling the unit cell along the b direction. A brownmillerite structure can be generated removing at least two oxygen atoms along the <100> direction of a perovskite structure as shown with the circle in Figure 1; the octahedral coordination of Mn ion becomes 4-fold and undertakes large relaxation in order to form the tetrahedral coordinated plane. The brownmillerite structure has lines of oxygen vacancies arranged in a simple cubic grid (in the b direction), whereas for the brownmillerite-like the oxygen vacancies lines are in a body centred grid. The two structures have however many similarities, both comprising layers of octahedral coordinated Mn$^{3+}$ and layers of 4-fold coordinated Mn$^{4+}$ ions with lines of oxygen vacancies along the a direction and an expansion in the volume of about 6.70%. The enthalpies of formation of Vo were calculated to be 1.50 eV for the brownmillerite-like and 1.57 eV for the brownmillerite structures respectively (the heats of reduction were calculated to be 0.75 and 0.78 eV respectively). The brownmillerite-like structure (Figure 3(a)) was also minimized with Mn ions in the oxidation states IV (6-fold coordinated) and II (4-fold coordinated) but the enthalpy of formation of Vo was calculated to be 1.72 eV (the heat of reduction was 0.82 eV) indicating that the mixed oxidation state for Mn gives rise to energetically less stable configurations. In configuration b (Fig. 3b) the oxygen vacancies are arranged in lines along the b direction producing a structure where all the Mn$^{3+}$ ions are 5-fold coordinated with a enthalpy of formation of Vo of 1.63 eV (the heat of reduction was 0.82 eV) and a volume expansion of 4.33%. Configuration c (Fig 3c) has layers of octahedral coordinated Mn$^{3+}$ and layers of squared planar coordinated Mn$^{3+}$ with oxygen vacancy lines along the ac direction. This configuration has the highest enthalpy of formation of Vo of 1.79 eV (heat of reduction of 0.89 eV) and one of the highest volume expansion of 6.64%. Finally, configuration d (Figure 3d) has an entire layer of oxygen removed in the ac plane and all Mn$^{3+}$ are 5-fold squared pyramidal coordinated. The volume expansion is the smallest from CaMnO$_3$ to this composition of 3.19% and the enthalpy of formation of Vo is 1.76 eV (heat of reduction is 0.88 eV). The two most stable configurations found for CaMnO$_{2.5}$ are the brownmillerite structures, however as they gave rise to similar transport properties we have selected only the brownmillerite-like and configuration b to be representative of the highly reduced CaMnO$_{2.5}$.

iii. Density of States

The partial density of states (PDOS) of stoichiometric and reduced CMO is displayed in Figure 4. For the purpose of this section it is not important to show the density of states for all the structures as there are common features depending on the composition not on the structure.

![Figure 4. PDOS on an arbitrary scale of stoichiometric (a), partially reduced (b) and reduced (c) CMO. The Fermi energy is at 0 eV.](image)

CaMnO$_3$ is an insulator with a measured band gap of 3.07 eV and the electron-band structure close to the
The Fermi level consisting of Mn d and O p orbitals. Figure 4a shows these features, however the band gap is largely underestimated (1.42 eV) which is a known issue with the methodology used. Upon partial reduction (Figure 4(b)) there are states appearing in the gap which are still dominated by O 2p and Mn 3d. The Mn states are filled and represent the Mn$^{3+}$. CMO shows insulating behaviour with a band gap of approximately 1.30 eV when fully reduced (Figure 4(c)). The Fermi level is still dominated by O 2p and Mn 3d but in this case all Mn atoms are in the oxidation state III.

The density of states is of importance as it gives information on the filled and empty energy levels. Thus, the energy scale of the DOS can be seen as a chemical potential with positive values representing the region of hole doping and negative values the region of electron doping. In Figure 6 the Fermi energy corresponds to chemical potential of 0eV which is also the top of the valence band (VB). Stoichiometric and partially reduced CMO can be electron doped showing n-type behaviour. The transport properties were therefore evaluated according to the Boltzmann semiclassical transport theory at values of the chemical potential corresponding to the bottom of the conduction band (CB). For details see ref 42. At this chemical potential the number of carriers for the studied CMO compositions was found to be of the order of $10^{20}$ cm$^{-3}$ and the temperature dependency is shown in Figure 5. Particular consideration has to be drawn for the highly doped CMO containing only Mn in the oxidation state $3^+$ as it could be treated as an n-type (Mn$^{2+}$ → Mn$^{3+}$) or p-type (Mn$^{3+}$ → Mn$^{4+}$). It was reported that Mn$_2$O$_3$ (all Mn$^{3+}$) and MnO$_2$ (all Mn$^{4+}$) are respectively p-type and n-type semiconductors. Furthermore Mn$_3$O$_4$ has a p-type behaviour. However, at the best of our knowledge there are no available data to support that highly reduced CMO is a p-type semiconductor. Thus, we calculated the transport properties in correspondence to the bottom of the CB where the material is an n-type semiconductor.

iv. The Seebeck Coefficient

The Seebeck coefficients as a function of T are shown in Figure 6 for all the compositions. These include stoichiometric CMO, the two configurations of CaMnO$_{2.75}$ and the two most stable configurations of the highly reduced CaMnO$_{2.5}$ (a and b). The comparison with experiments is not straightforward as the Seebeck depends on the number of carriers which is dependent on the nature of the sample. The values of our calculated S are at the chemical potential corresponding to the bottom of the CB which can be achieved at different carrier concentrations of electrons. Therefore our approach is to describe the differences between the Seebeck coefficients for our structures highlighting those with improved Seebeck to guide possible choices when synthesizing experimental samples. However, discussion of available experimental data is given and where possible, similarities are compared.

Figure 6. Seebeck coefficient of stoichiometric and reduce CMO as a function of the temperature.

![Seebeck Coefficient Graph](image)

The calculated S for CaMnO$_3$ decreases in absolute value as the temperature increases. The same trend is seen for both highly reduced CaMnO$_{2.5}$ configurations with the brownmillerite-like structure performing better than the configuration b for highly reduced CMO. However the absolute value is now reduced compared to CaMnO$_3$. In contrast to the stoichiometric and the highly reduced CMO, CaMnO$_{2.75}$ shows an increase of the absolute value of the Seebeck coefficient with the increase in temperature. These trends and values are similar to some of the experimental doped samples. The zig-zag configuration has a higher absolute value of S compared to the structure with lines of oxygen vacancies. This again highlights the importance of defect arrangements. For improved S the best composition is the partially doped CMO with a zig-zag arrangement of oxygen vacancies showing a flat curve in the temperature range between 550 and 850K. Constant TE properties in the range of operating temperatures are indeed desired.

It is worth noting that our simulations indicate that there are two distinct trends in the variation of the Seebeck coefficient with temperature. The calculations predict that the Seebeck coefficient decreases with increasing temperature for the mixed oxidation states phases (CaMnO$_{2.75}$) while for the stoichiometric and fully reduced phases (comprising only Mn$^{4+}$ or Mn$^{3+}$) the Seebeck coefficient is predicted to increase with
increasing temperature. The Seebeck coefficient is related to the gradient of the density of states at the bottom of the conduction band. In the case of fully oxidised and fully reduced phases the conduction band comes from all of the metal states while in partially reduced phase the metal states are split coming from both Mn$^{3+}$ and Mn$^{4+}$ states. This reduced density will contribute to the change in the gradient of the density of states at the bottom of the conduction band.

The experimental data in the literature show a wide spread of values and different trends. Cohn et al measured the Seebeck coefficient for a single crystal of CMO of -550 μV/K decreasing to -800 μV/K in the range of temperature between 300 and 100K. The value at 300K is much higher than any of our values at the same temperature. Alfaruq et al measured the S two polycrystalline CMO (impurities in the samples include CaMnO$_2$, and CaMn$_2$O$_4$ phases) seeing a sharp reduction in absolute value with increasing temperature to 500K and reaching a plateau beyond to values of approx. -300 and -170 μV/K depending on the sample. These values are broadly in the same region of ours. Similarly, Lan et al, Xu et al and Flahaut et al measured the S for polycrystalline CMO (likely reduced or containing impurities) decreasing in absolute values with temperature. This is the same trend we see for the stoichiometric and highly reduced CMO. Finally, Liu et al measured the Seebeck coefficient for a polycrystalline CaMnO$_{3.4}$ samples decreasing with temperature which is in good agreement with our partially reduced compositions.

It is therefore clear that the large differences between the experimental data is due to the presence of impurities and/or reduced CMO along with extended defects such as grain boundaries in polycrystalline samples. It is worth emphasizing that the simulated structures do not contain any extended defects (grain boundaries).

v. The Electronic Resistivity

The evaluation of the electronic resistivity is complicated by requiring the relaxation time ($\tau_0$). However, the value of $\tau_0$ only applies a constant shift to all of the resistivity curves for all the compositions studied; i.e. leaving the differences between the structures unchanged. Experimental evaluation of the relaxation time is not trivial and a $\tau_0 = 7.5 \times 10^{-14}$ s was calculated for a polycrystalline film of cubic CMO which is greater than $10^{15}$-$10^{16}$ s reported in 49 and one order of magnitude greater than $\tau_0 = 4.3 \times 10^{15}$ s derived for the perovskite SrTiO$_3$. We chose $\tau_0 = 0.5 \times 10^{16}$ s for all temperatures which brought the resistivity of all our phases in the range of those measured by Loshkareva et al for reduced single crystals of cubic CMO in the range of 150 to 400K. Figure 7 shows the corrected data for all the compositions studied as a function of temperature.

Before describing our data, it is worth mentioning that there is a broad spread of experimental data for both single crystal and polycrystalline specimens. This implies that the compositions and the distribution of oxygen vacancies in the grains as well as the grain boundaries have great effect on the measurements. CMO was found to have substantial electronic resistivity at room temperature. 2.7 Ω cm and 1.5 Ω cm were reported for single crystals and 1 Ω cm for polycrystalline material depending on the concentration and ordering of vacancies. Xu et al also reported a resistivity of approx. 2 Ω cm at 400K down from 8 Ω cm at room T. Flahaut et al reported values of approx. 0.25 Ω cm between 600 and 700K down from 0.5 Ω cm at room temperature for a polycrystalline material. All these values are broadly in the range of our corrected data, suggesting that the choice of a relaxation time was appropriate. Thus we infer that our data can be used to discriminate between different compositions and most importantly between different arrangements of oxygen vacancies.

We can divide our structures into two groups. The “high resistance” group includes the partially reduced configuration with lines of oxygen vacancies and the highly reduced brownmillerite-like structure while the “low resistance” group comprises the highly reduced b structure. Considering that the brownmillerite-like structure has never been reported, therefore despite being thermodynamically the most stable structure it might be kinetically not accessible, we suggest that one possible arrangement of oxygen vacancies in their sample was alike the simulated partially reduced configuration with lines of oxygen vacancies. Furthermore, their “low resistance” sample, which shows resistivity values comparable to our highly reduced b structure and partially reduced zig-zag configuration, was supposed to have possibly a higher concentration of oxygen vacancies and less ordered arrangement, which is in agreement with our two simulated structures. While we recognize that the choice of relaxation time shifted our data in the range of Loshkareva et al, it is remarkable how this choice has brought our data broadly close to most of the available experimental data and most importantly gives a possible interpretation of the experimental data in “low” and “high resistance” samples.

From our data we have also calculated the activation energy for electron from $\sigma = (\sigma_0/T) \exp(-E_a/K_bT)$ to be $0.07 - 0.08$ eV for the all the compositions. However this is lower compared to the experimental values of 0.16 and 0.22 eV. The difference can be ascribed to the presence of impurities and to the nature of the polycrystalline sample used for the measurement.

Figure 7. Electrical resistivity of stoichiometric and reduce CMO as a function of the temperature calculated using a relaxation time of $0.5 \times 10^{16}$ s.
vi. The Power Factor

Figure 8 shows the power factor (S²σ) as a function of T. Lan et al.⁶⁹ reported values of approx. 0.06 μW/cmK² below 750K and a sharp raise above 800K up to 0.5 μW/cmK² at approximately 1000K. All our data are in within this range. However there is a broad range of experimental data. Ohtaki et al.⁷⁵ measured approximately 0.2 and 0.8 μW/cmK² at 200 and 700K respectively while Alfaruq et al.⁶⁸ reported values of 0.085 – 0.065 μW/cmK² at 1000 K which are one order of magnitude lower then Lan et al. Again we must be cautious with direct comparison with experimental data from polycrystalline materials. However our data show that the stoichiometric CMO has the highest PF due to the high S and the low resistivity (due to the high concentration of carriers as shown in Figure 5) while the brownmillerite-like structure has the lowest due to a combination of low S and high resistivity. However the remaining structures have comparable values. The partially reduced configuration with lines of oxygen vacancies has an acceptable PF due to the high S despite showing the highest resistivity. The highest power factor is shown by the partially reduced composition with zig-zag arrangement of oxygen vacancies due to a high S and low resistivity.

Figure 8. Power Factor of stoichiometric and reduce CMO as a function of the temperature calculated using a relaxation time of 0.5x10⁻¹⁶ S.

vii. The Figure of Merit

The figure of merit (ZT) can be calculated as in Equation 1; however before describing our results we detail our approximation in order to calculate the denominator.

The thermal conductivity (k = k_l + k_e) is the sum of the electronic component k_e (calculated with a relaxation time of 0.5 x 10⁻¹⁶ s) and the lattice component k_l. However as the former is negligible compared to the latter (several order of magnitude), k_l is mainly assigned to the lattice contribution. The electronic contribution was calculated using the BoltzTraP code while the lattice contribution with the Phonopy code as detailed in the methodology. However the calculation of k_l is extremely computationally expensive and therefore was performed only on the stoichiometric CMO. The calculated values as a function of temperature (Figure 9) are extremely close to the experimental values of Flahaut et al.⁷¹, Ohtaki et al.⁷⁵ and Xu et al.⁷⁰ who measured a decrease in the value of k with increasing T.

Figure 9. Lattice thermal conductivity (μW/cmK) of stoichiometric and reduce CMO as a function of the temperature.

Therefore we have used the thermal conductivity calculated of the stoichiometric sample for all the structures. This is clearly an approximation as the presence of defects influences the thermal conductivity. Figure 10 shows the ZT as a function of the temperature.

Figure 10. Figure of merit of the stoichiometric and reduce CMO as a function of the temperature.

ZT show the same trend as the PF with the stoichiometric CMO showing the highest and the highly reduced brownmillerite-like structure the lowest achievable figure of merit.

The experimental values of Flahaut et al.⁷¹ are significantly higher the ours with a ZT lower than 0.01.
and higher that 0.04 at 350 and 950K respectively.

IV. Conclusions

As perovskite oxides are promising TE materials we have investigated local structures of a candidate material CaMnO$_3$, which shows inhomogeneity with areas generally rich in oxygen vacancies and cracking. In order to model this material we have applied DFT to the structures of different compositions of CaMnO$_{3-x}$. The thermodynamically most stable partially reduced configuration does not show ordered lines of oxygen vacancies while the most stable highly reduced structure is a brownmillerite-like which also shows the highest volume expansion. All these structures show volume expansion which suggest that the formation of domains within the material would be responsible for the cracking observed. The brownmillerite-like structure has never been reported experimentally and thus we infer that despite being thermodynamically the most stable it might not be kinetically accessible. We then evaluated the transport properties of these structures to examine the different impact on the thermoelectric behaviour of CMO samples. Unlike the stoichiometric and fully reduced phases, the partially reduced structures show the Seebeck coefficient to increase (in absolute value) with increasing the temperature. This might be due to the presence of mixed oxidation states which is likely to influence the gradient of the density of states at the bottom of the conduction band. Indeed, this feature might be a general phenomenon in phases with mixed oxidation states which is worthy of further investigation. We found that the partially reduced structure has the highest Seebeck coefficient. However, the ordering of oxygen vacancies in lines increases the resistivity of the structure but as the S is high the power factor (S$^2$σ) is still comparable to the partially reduced (zig-zag) structure with lower ordering of oxygen vacancies. We found that there are three structures with comparable power factor and figure of merit which comes out of an inter-play of thermoelectric properties. These two properties are however not constant in a large range of temperature as desirable from an ideal thermoelectric material. The results suggest that although these local structures with enriched ordering of oxygen vacancies might be of importance for other applications they are undesirable for thermoelectric applications of doped CMO samples.

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